## NSN 5961-00-006-1519

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View Online at https://aerobasegroup.com/nsn/5961-00-006-1519 **Inclosure Material:** Metal **Overall Length:** 1.153 inches **Overall Diameter:** 0.562 inches **Mounting Facility Quantity: Internal Configuration:** Unijunction **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 25.00 amperes collector current, dc megahertz **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Special Features:** Junction pattern arrangement: npnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0